

N-Channel Silicon MOSFET

**2SK1460**

## Ultrahigh-Speed Switching Applications

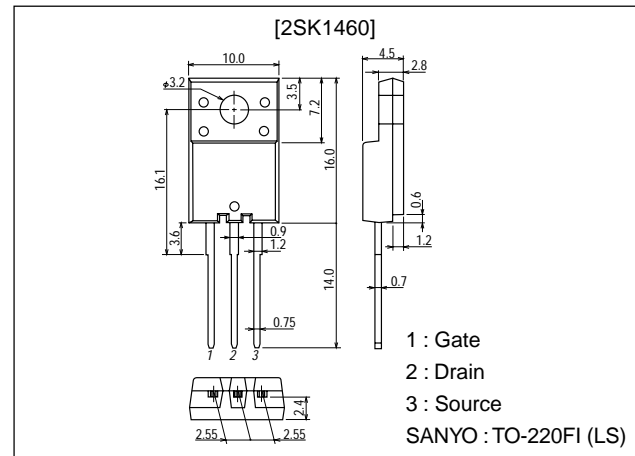
### Features

- Low ON-state resistance.
- Ultrahigh-speed switching.
- Micaless package facilitating mounting.

### Package Dimensions

unit:mm

2078B



### Specifications

#### Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	$V_{DSS}$		900	V
Gate-to-Source Voltage	$V_{GSS}$		±30	V
Drain Current (DC)	$I_D$		3.5	A
Drain Current (Pulse)	$I_{DP}$	$PW \leq 10 \mu s$ , duty cycle $\leq 1\%$	7	A
Allowable Power Dissipation	$P_D$		2.0	W
		$T_c = 25^\circ C$	40	W
Channel Temperature	$T_{ch}$		150	°C
Storage Temperature	$T_{stg}$		-55 to +150	°C

#### Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Drain-to-Source Breakdown Voltage	$V_{(BR)DSS}$	$I_D = 1mA$ , $V_{GS} = 0$	900			V
Zero-Gate Voltage Drain Current	$I_{DSS}$	$V_{DS} = 900V$ , $V_{GS} = 0$			1.0	mA
Gate-to-Source Leakage Current	$I_{GSS}$	$V_{GS} = \pm 30V$ , $V_{DS} = 0$			±100	nA
Cutoff Voltage	$V_{GS(off)}$	$V_{DS} = 10V$ , $I_D = 1mA$	2.0		3.0	V
Forward Transfer Admittance	$ y_{fs} $	$V_{DS} = 20V$ , $I_D = 2A$	1.0	2.0		S
Static Drain-to-Source ON-State Resistance	$R_{DS(on)}$	$I_D = 2A$ , $V_{GS} = 10V$		2.8	3.6	$\Omega$

(Note) Be careful in handling the 2SK1460 because it has no protection diode between gate and source.

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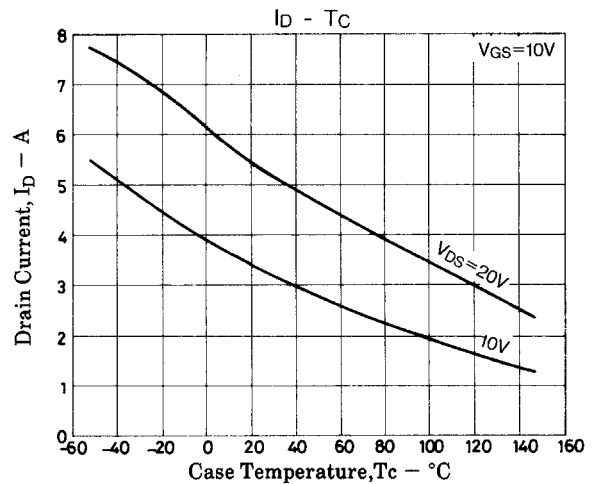
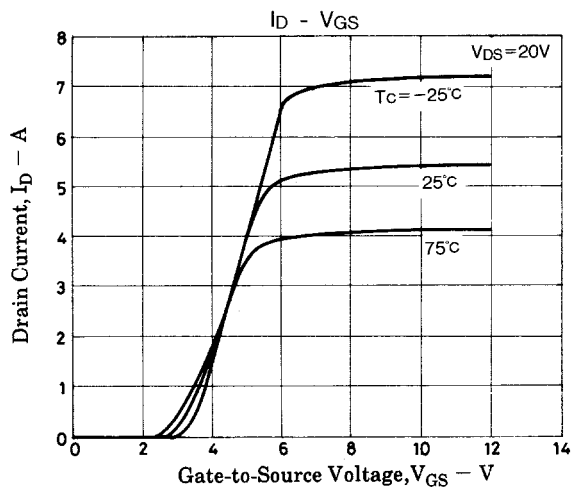
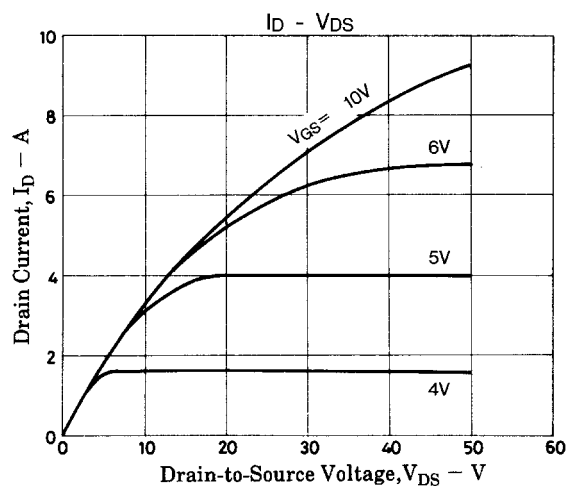
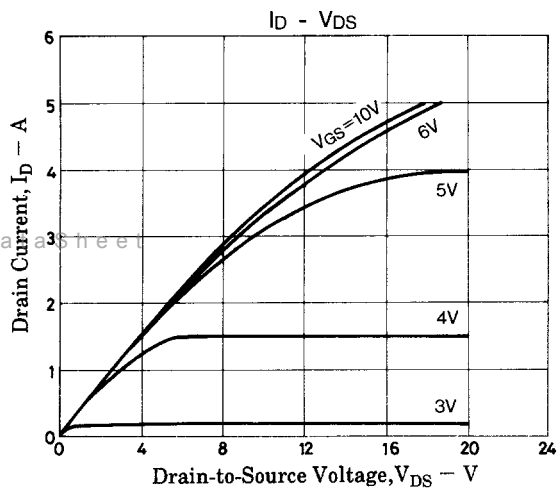
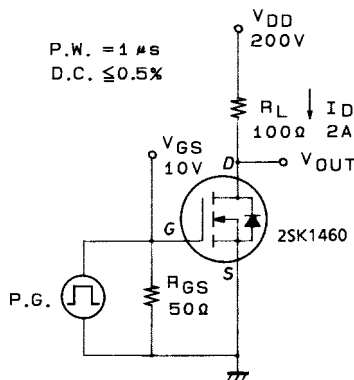
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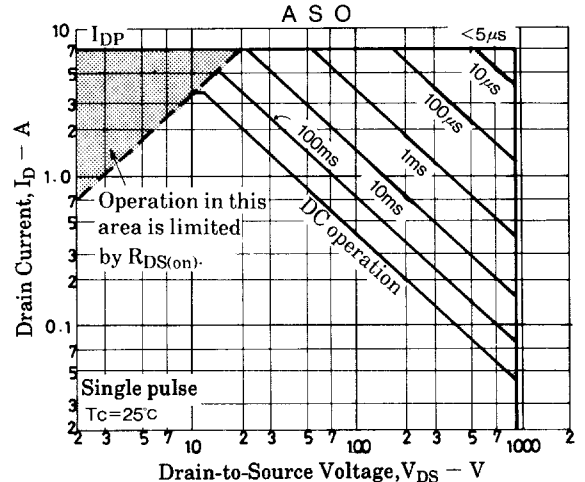
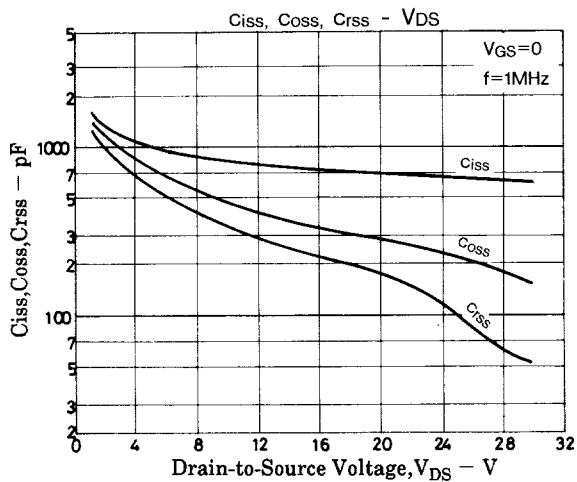
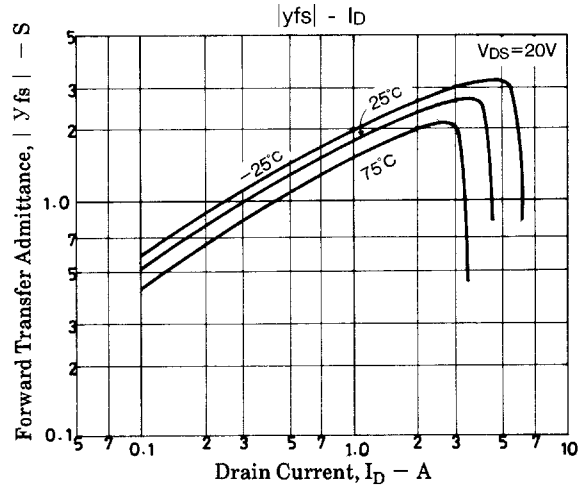
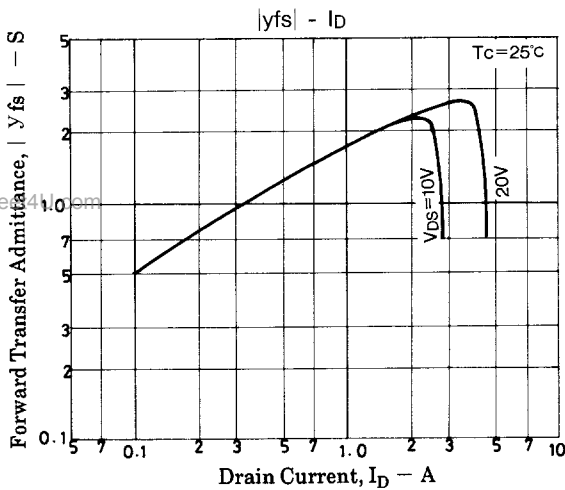
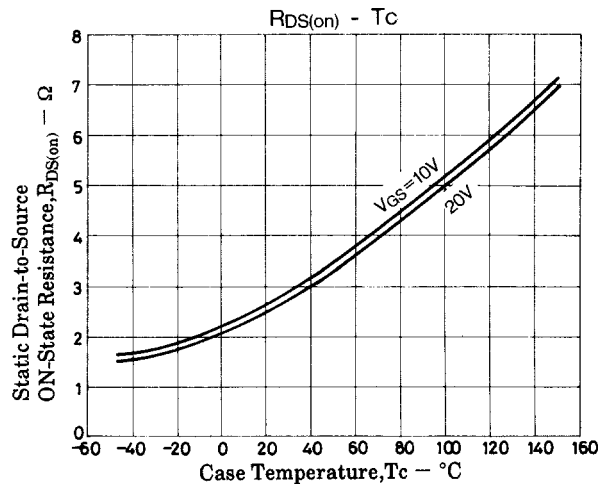
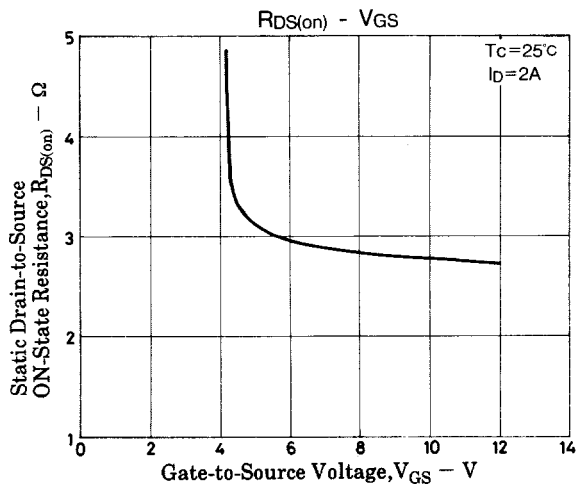
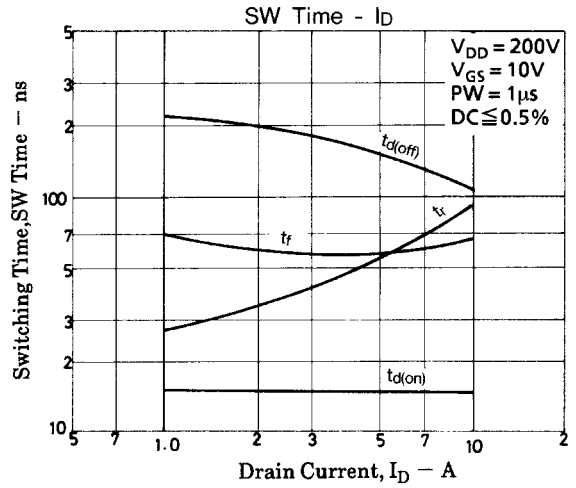
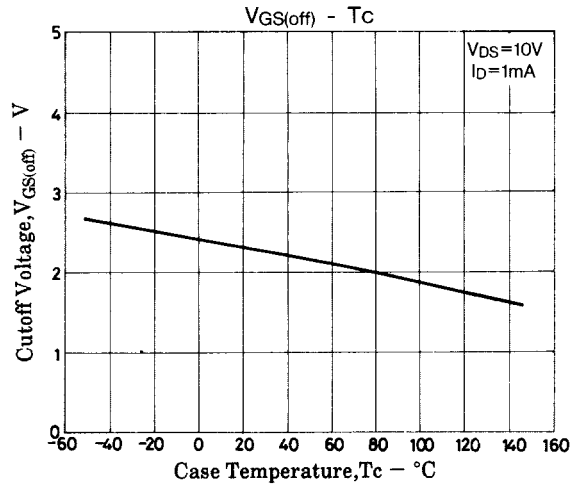
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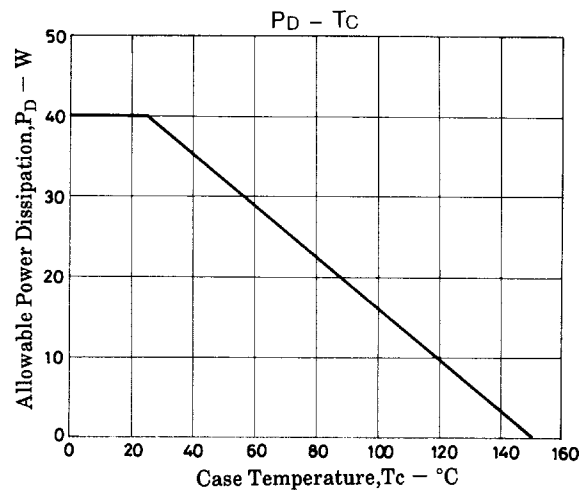
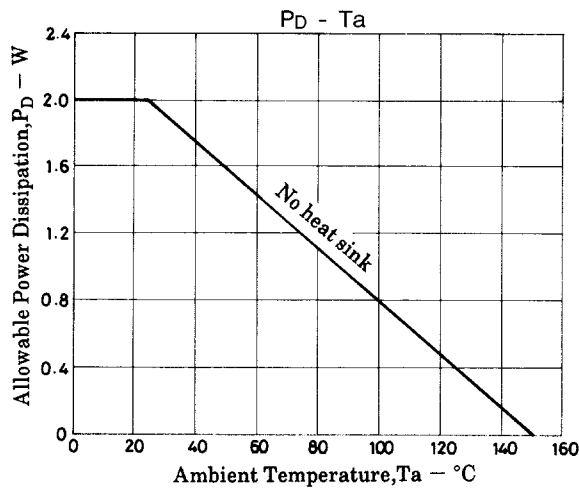
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Input Capacitance	Ciss	$V_{DS}=20V, f=1MHz$		700		pF
Output Capacitance	Coss	$V_{DS}=20V, f=1MHz$		300		pF
Reverse Transfer Capacitance	Crss	$V_{DS}=20V, f=1MHz$		170		pF
Turn-ON Delay Time	$t_{d(on)}$	$I_D=2A, V_{GS}=10V, V_{DD}=200V, R_{GS}=50\Omega$		15		ns
Rise Time	$t_r$	$I_D=2A, V_{GS}=10V, V_{DD}=200V, R_{GS}=50\Omega$		35		ns
Turn-OFF Delay Time	$t_{d(off)}$	$I_D=2A, V_{GS}=10V, V_{DD}=200V, R_{GS}=50\Omega$		200		ns
Fall Time	$t_f$	$I_D=2A, V_{GS}=10V, V_{DD}=200V, R_{GS}=50\Omega$		65		ns
Diode Forward Voltage	$V_{SD}$	$I_S=3.5A, V_{GS}=0$			1.8	V

## Switching Time Test Circuit





## 2SK1460



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